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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/082,634	02/21/2002	Selena Chan	176/61011 (2-11144-1010)	4466
7590 08/02/2006			EXAMINER	
Michael L. Goldman			FORMAN, BETTY J	
NIXON PEABODY LLP Clinton Square			ART UNIT	PAPER NUMBER
P.O. Box 31051			1634	
Rochester, NY 14603-1051			DATE MAILED: 08/02/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 25 May 2006 has been entered.

Claims 1-21, 34 and 46-47 are under prosecution.

2. All claims are drawn to the same invention claimed in the application prior to the entry of the submission under 37 CFR 1.114 and could have been finally rejected on the grounds and art of record in the next Office action if they had been entered in the application prior to entry under 37 CFR 1.114. Accordingly, **THIS ACTION IS MADE FINAL** even though it is a first action after the filing of a request for continued examination and the submission under 37 CFR 1.114. See MPEP § 706.07(b). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

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Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

4. Claims 1, 20, 21, 34 and 46 are rejected under 35 U.S.C. 102(b) as being anticipated by Groger et al. (U.S. Patent No. 5,577,137, issued 19 November 1996).

Regarding Claim 1, Groger et al disclose a porous structure comprising a central layer (i.e. waveguide #3) interposed between upper and lower layers having layers of alternating porosity i.e. Bragg reflector (Column 4, lines 33-35 and 40-64) and one or more probes coupled to the porous structure whereby detectable change occurs in a refractive index upon probe binding (Column 2,lines 2-24; Column 5,lines 52-67; Column 8, lines 18-32 and Fig. 9).

It is noted that instant Claim 46 defines the upper and lower layers as Bragg reflectors.

Groger et al teach the layers are Bragg reflectors. Therefore, Groger teaches the claimed layers.

Regarding Claim 20, Groger et al disclose the structure comprising two ore more different probes i.e. multiple receptors (Column 4, lines 19-25).

Regarding Claim 21, Groger et al disclose the structure comprising two ore more different probes in different zones i.e. multiple receptors in the patterned wave guide (Column 4, lines 19-25; Column 5, lines 3-5 and 52-67).

Regarding Claim 34, Groger et al disclose a detection device comprising the structure of Claim 1, a source of illumination and a detector (Claim 1).

Regarding Claim 46, Groger et al disclose the upper and lower layers are Bragg reflectors (Column 4, lines 33-35).

Response to Arguments

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5. Applicant argues that Groger fails to teach a sensor that includes a porous semiconductor as required by the instant claims. The argument has been considered but is not found persuasive because as cited above, the instant specification broadly defines the claimed semiconductor structure as including a Bragg reflector (page 6, lines 10-27).

The porous semiconductor structure includes a central layer (a microcavity) interposed between upper and lower layers, each of the upper and lower layers including strata of alternating porosity. The upper and lower layers form Bragg reflectors.

Semiconductors which can be used to form the porous semiconductor structure can be a single semiconductor material, a combination of semiconductor materials which are unmixed, or a mixture of semiconductor materials. The semiconductor is preferably one which is photoluminescent in its porous state. By virtue of the Bragg reflectors (i.e., the upper and lower layers), the emitted photoluminescence spectrum is composed of multiple sharp and narrow peaks. The light can be in the visible portion of the electromagnetic spectrum (i.e., 350-800 nm), the infrared region (i.e., 800-3000 nm), and the ultraviolet region (i.e., 50-350 nm). These wavelengths are only exemplary and can vary according to the type of semiconductor materials) used to form the porous semiconductor structure, the thickness thereof, as well as the porosity thereof (including pore size).

Preferred semiconductors which can be used to form the porous semiconductor structure include, without limitation, silicon and silicon alloys.

The claims require a porous semiconductor structure comprising a central layer interposed between up and lower layer having strata of alternating porosity. As such, the claims define the structure as having layers of alternating porosity. The claims do not require any specific semiconductor materials other than the alternating layers. The specification, as noted above, defines the alternating layers as encompassing a Bragg reflector. Groger teaches a Bragg reflector (Column 4, lines 33-35 and 40-64) and therefore teaches the structure as claimed. While the specification further teaches some preferred materials for the semiconductors, these preferred embodiments are not read into the claims.

Applicant further argues that the sensor of Groger operates by detecting fluorophores while the instantly claimed sensor operates by detecting a change in refractive index. The argument has been considered but is not found persuasive because the intended us of the apparatus does not define the apparatus. The courts have stated that an apparatus must be defined by its structure.

A claim containing a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all the structural limitations of the claim. Ex parte Masham, 2 USPQ2d 1647 (Bd. Pat. App. & Inter. 1987).

Because Groger teaches all the structural limitations of the claim, they teach the claimed sensor.

Allowable Subject Matter

6. Claims 2-19 and 47 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

- 7. No claim is allowed.
- 8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to BJ Forman whose telephone number is (571) 272-0741. The examiner can normally be reached on 6:00 TO 3:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Ram Shukla can be reached on (571) 272-0735. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to (571) 272-0547.

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BJ Forman, Ph.D. Primary Examiner Art Unit: 1634 July 28, 2006